

Photoluminescence Emission Studies on a Lanthanum-Doped Lead Free Double Halide Perovskite, La:Cs₂SnCl₆

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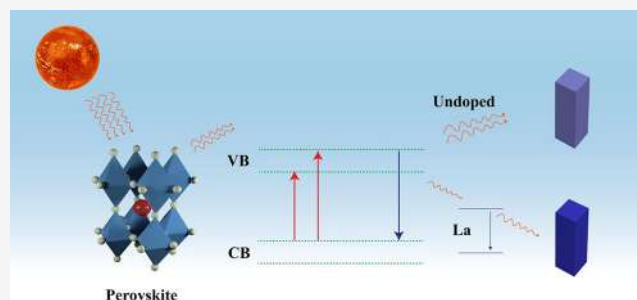


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ABSTRACT: Recent advances in bandgap engineering have increased the possibility of vacancy ordered double halide perovskites (VO-DHPs), Cs₂SnX₆ where X = Cl, Br, I with designable optoelectronic features. Doping with La³⁺ ions modulates the band gap from 3.8 to 2.7 eV, allowing a steady room temperature dual emission (PL) centered at 440 and 705 nm in Cs₂SnCl₆. Pristine Cs₂SnCl₆ and La:Cs₂SnCl₆ both have a crystalline cubic structure with a space symmetry of *Fm3m*. The cubic phase correlates well with the Rietveld refinement. SEM analysis confirms anisotropic development with huge micrometer-sized (>10 μm) truncated octahedral structures. DFT investigations show that the insertion of La³⁺ ions into the crystal lattice causes the band splitting. The present study elaborates the experimental understanding of the dual PL emission properties of La:Cs₂SnCl₆ leaving a scope for detailed theoretical study on the origin of the complex electronic transitions involving f-orbital electrons.



INTRODUCTION

Lead halide perovskites (LHP) are considered to be the most prominent and promising materials for optoelectronics and more specifically for photovoltaic applications.^{1–5} Methylammonium lead halide perovskites (CH₃NH₃PbX₃) and their all-inorganic counterparts, cesium lead halide perovskites (CsPbX₃), where X = Cl, Br, and I, have been intensively researched for their outstanding photophysical characteristics.^{6–8} However, they face serious environmental concerns of Pb toxicity and inherent instability before they would be able to find commercial success.^{9,10} To overcome this, several attempts have been made to replace two Pb²⁺ ions by one monovalent metal ion (M⁺: Li⁺, Ag⁺, Na⁺, K⁺, etc.) and one trivalent metal ion (M³⁺: In³⁺, Sb³⁺, Bi³⁺) that results in formation of the structure Cs₂M⁺M³⁺X₆.^{9,11–14} The strategy for the replacement of Pb²⁺ with Sn²⁺ ions is not successful due to the intrinsic elemental tendency for oxidation to the more stable Sn⁴⁺.^{15,16} However, the direct replacement of Pb²⁺ with Sn⁴⁺ forms an interesting class of materials referred as vacancy ordered double halide perovskites (VO-DHP) and is represented by Cs₂SnX₆.^{17,18} The unique crystal structure of Cs₂SnCl₆ has vacancies at the B sites of conventional ABX₃ perovskites, resulting in corner-sharing [BX₆] octahedral crystal structures that warrant extensive theoretical and experimental investigations for their structural and thermal stability.¹⁹ Unlike the homologous series of Cs₂SnI₆, Cs₂SnCl₆ has generated little interest initially due to its large band gap exceeding 3.8 eV.^{20–23} However, the recent advancement in band gap engineering that leads to exciting photophysical properties has widened the possibilities of these materials in

optoelectronics.²⁴ For instance, blue, yellow, and red emission has been reported for nanocrystals of Cs₂SnCl₆ upon doping with Bi³⁺, Te⁴⁺, and Sb³⁺ ions, respectively.²⁵ Interestingly, the nanocrystals exhibit white light emission when Cs₂SnCl₆ is codoped with Bi³⁺ and Te⁴⁺.²⁶ Sb³⁺ doping induced orange emission from Cs₂SnCl₆ has also been reported which underlines the mechanism of the emission process.²⁷ At cryogenic temperatures, Sb³⁺ doped in Cs₂SnCl₆ has two emission peaks, while Bi³⁺ doping exhibits just one.²⁸ In this study, we investigate the photophysical effects of doping in Cs₂SnCl₆ with La³⁺ and compare the results with previous studies on doping with Bi³⁺ and Sb³⁺. Our findings demonstrate that doping with La³⁺ leads to a significant increase in the luminescence intensity, compared to the doping with Bi³⁺ and Sb³⁺. Additionally we observed a Moss–Burstein effect in the emission peak upon La³⁺ doping.³⁹ These results provide new insights into the photophysical properties of Cs₂SnCl₆ doped with various lanthanoid ions, highlighting the potential of La³⁺ as a dopant for improving the luminescence properties of Cs₂SnCl₆. Recently, in an interesting study, it has been demonstrated that pressure can significantly alter the structural characteristics of VO DHPs

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